

## Silicon Carbide Schottky Barrier Diode



#### Features

- Temperature Independent Switching Behavior
- High Surge Current Capability
- Positive Temperature Coefficient on VF
- Low Conduction Loss
- Zero Reverse Recovery
- High junction temperature 175 °C
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### **Mechanical Data**

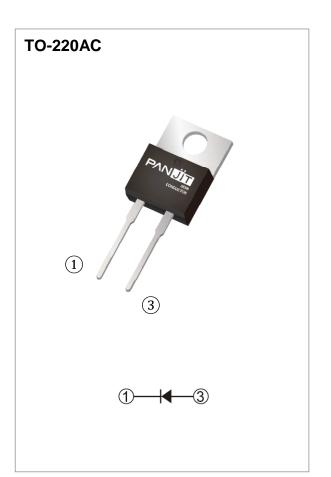
- Case: TO-220AC molded plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.067 ounces, 1.89 grams

### Application

• PFC, UPS, PV Inverter, EV Charging Station, Welder

## Maximum Ratings and Thermal Characteristics (Tc = 25 °C unless otherwise specified)

PARAMETE	SYMBOL	LIMIT	UNITS		
Repetitive Peak Reverse Voltage	Vrrm	1200	V		
DC Blocking Voltage	V <sub>DC</sub>	1200	V		
Continuous Forward Current	Tc= 150 °C	lF	20	А	
Repetitive Peak Surge Current	$T_{C}=25 \circ C$ , $t_{p}=10 ms$		76		
Half Sine Wave, D=0.1	$T_C=125 \ ^{\circ}C$ , $t_p =10ms$	IFRM	56	A	
Peak Forward Surge Current	$T_C= 25 \circ C$ , $t_p = 10 ms$		152	А	
Half Sine Wave	$T_C=125 \ ^{\circ}C$ , $t_p =10ms$		128		
Peak Forward Surge Current $t_p = 10us$ , Pulse	IFSM	960	A		
Maximum Power Dissipation	P <sub>total</sub>	267.9	W		
Operating Junction Temperature Ra	TJ	-55~175	°C		
Storage Temperature Range	Tstg	-55~175	٥C		





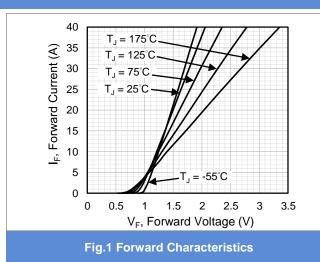
# **Electrical Characteristics** ( $T_c = 25$ °C unless otherwise specified)

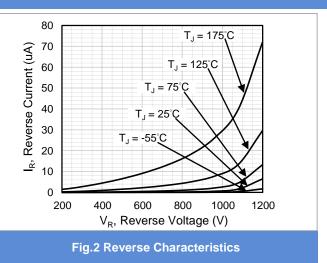
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Forward Voltage Drop	VF	I <sub>F</sub> = 20 A, T <sub>J</sub> = 25 °C	-	1.5	1.7	- V	
		I <sub>F</sub> = 20 A, T <sub>J</sub> = 175 °C	-	2.0	-		
Reverse Leakage Current	I <sub>R</sub>	V <sub>R</sub> = 1200 V, T <sub>J</sub> = 25 °C	-	15	180	μA	
		V <sub>R</sub> = 1200 V, T <sub>J</sub> = 175 °C	-	0.07	-	mA	
Total Capacitive Charge	Qc	I <sub>F</sub> = 20 A, V <sub>R</sub> = 800V	-	87	-	nC	
Total Capacitance	С	$V_R = 1V$ , f = 1MHz	-	1040	-	pF	
		V <sub>R</sub> = 400V, f = 1MHz	-	77	-	pF	
		V <sub>R</sub> = 800V, f = 1MHz	-	57	-	pF	
Capacitance Stored Energy	Ec	V <sub>R</sub> = 800V	-	25.8	-	μJ	
Thermal Resistance	Rejc		-	0.56	-	°C/W	

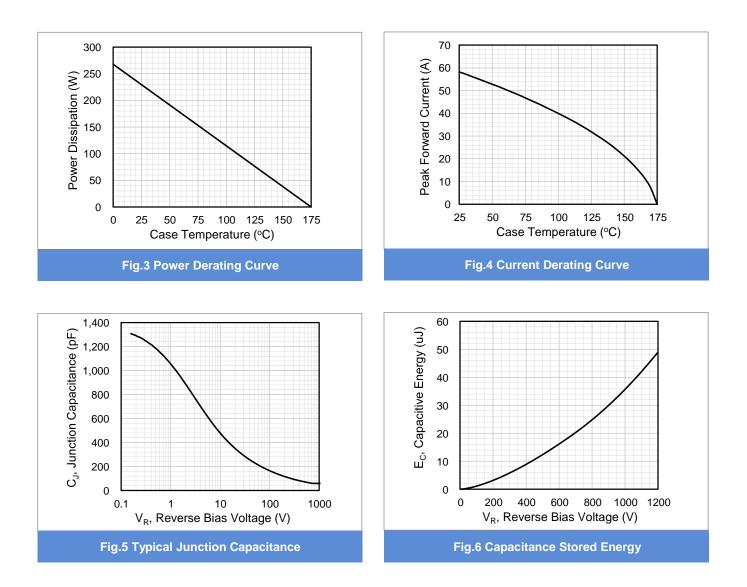


# PCDP20120G1







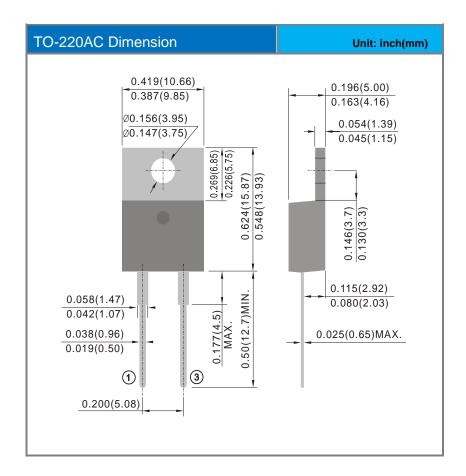




### **Product and Packing Information**

Part No. Package Type		Packing Type	Marking	
PCDP20120G1	TO-220AC	50pcs / Tube	CDP20120G1	

### **Packaging Information**





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